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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

) Art Unit: 2811

Tatsuya ARAO et al.

) Examiner: T. Tran

Serial No. 09/826,416

)

Filed: April 5, 2001

)

For: SEMICONDUCTOR DEVICE AND)
MANUFACTURING METHOD)
THEREOF)

AMENDMENT

Honorable Commissioner of Patents

Washington, D.C. 20231

Sir:

In response to the Official Action dated December 13, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend the claims as follows:

2. (Amended) A semiconductor device comprising:

a first wiring and a second wiring formed of a first conductive film on an insulating surface;

a second conductive film formed on the first and second wirings so as to correspond thereto;

a pair of first semiconductor films of one conductivity type formed on the second conductive film;

a second semiconductor film formed on and extending between the pair of first semiconductor films;

an insulating film formed on the second semiconductor film; and

a third conductive film formed on the insulating film,